



#### **Product Summary**

BV <sub>DSS</sub>	Max R <sub>DS(ON)</sub>	<b>Max I</b> D @ T <sub>A</sub> = +25°C
	1Ω @ Vgs = -4.5V	-0.62A
-30V	1.5Ω @ V <sub>GS</sub> = -2.5V	-0.5A
	2Ω @ V <sub>GS</sub> = -1.8V	-0.44A

### **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

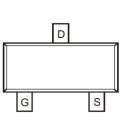
Load switches in portable electronics

#### SOT23



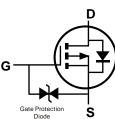


Top View



Top View

Internal Schematic



Equivalent Circuit

### Ordering Information (Note 4)

Part Number	Package	Pa	cking
Fait Nulliber	Fackage	Qty.	Carrier
DMP31D1U-7	SOT23	3,000	Tape & Reel
DMP31D1U-13	SOT23	3,000	Tape & Reel

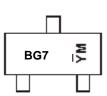
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimonv compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



BG7 = Product Type Marking Code  $\overline{Y}M = Date Code Marking$  $\overline{Y}$  = Year (ex: J = 2022) M = Month (ex: 9 = September)

#### Date Code Key

Year	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	J	K	L	М	N	0	Р	R	S	Т	U	V
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

DMP31D1U Datasheet number: DS44735 Rev. 3 - 2

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#### **30V P-CHANNEL ENHANCEMENT MODE MOSFET**

#### **Features and Benefits**

- Low Gate Threshold Voltage
- Fast Switching Speed
- **ESD** Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

#### **Mechanical Data**

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)



#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Ch	aracteristic		Symbol	Value	Unit
Drain-Source Voltage			Vdss	-30	V
Gate-Source Voltage			Vgss	±8	V
Continuous Drain Current	Steady State	$T_A = +25^{\circ}C$ (Note 5) $T_A = +70^{\circ}C$ (Note 5)	lD	-0.62 -0.5	А
Maximum Continuous Body Diode Forward Current (Note 5)			Is	-0.65	A
Pulsed Drain Current (10µs F	ulse, Duty Cy	cle = 1%)	ldм	-2	A

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 6)		PD	0.46	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>0JA</sub>	274	°C/W
Total Power Dissipation (Note 5)		PD	0.58	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	214	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

#### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

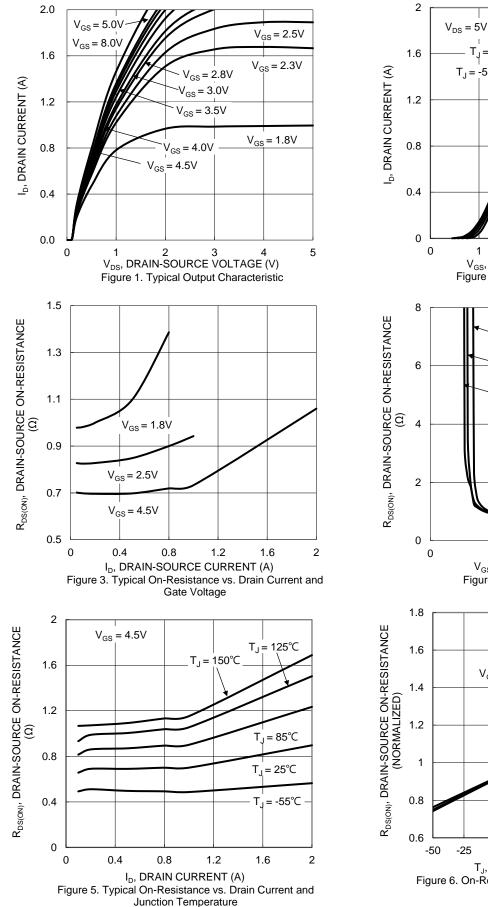
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	•					·
Drain-Source Breakdown Voltage	BVDSS	-30	_	_	V	$V_{GS} = 0V, I_D = -250 \mu A$
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	IDSS	—	_	-1	μA	V <sub>DS</sub> = -30V, V <sub>GS</sub> = 0V
Gate-Source Leakage	IGSS	—	—	±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(th)	-0.5	_	-1.1	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$
			0.6	1		$V_{GS} = -4.5V, I_{D} = -400mA$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	—	0.8	1.5	Ω	$V_{GS} = -2.5V, I_D = -200mA$
			0.9	2		V <sub>GS</sub> = -1.8V, I <sub>D</sub> = -100mA
Diode Forward Voltage	Vsd	_	-0.8	-1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -300mA
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	—	54	_	pF	
Output Capacitance	Coss	—	10.9	_	pF	Vps = -15V, Vgs = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	—	5.8	—	pF	
Total Gate Charge	Qg	—	1.0	_	nC	$V_{GS} = -4.5V, V_{DS} = -15V, I_{D} = -1A$
Total Gate Charge	Qg	—	1.6	_	nC	
Gate-Source Charge	Qgs	_	0.2	_	nC	Vgs = -8V, Vds = -15V Id = -1A
Gate-Drain Charge	Q <sub>gd</sub>	_	0.1	_	nC	ID = -IA
Turn-On Delay Time	t <sub>D(ON)</sub>		3.8	_	ns	
Turn-On Rise Time	tR	_	11	_	ns	V <sub>DD</sub> = -10V, R <sub>L</sub> = 10Ω
Turn-Off Delay Time	tD(OFF)	_	45	_	ns	$V_{GS}$ = -4.5V, $R_G$ = 6 $\Omega$
Turn-Off Fall Time	tF	_	20	_	ns	

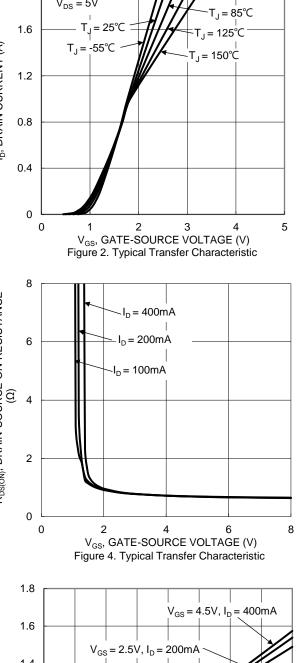
Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.



## DMP31D1U





T<sub>J</sub>, JUNCTION TEMPERATURE (°C) Figure 6. On-Resistance Variation with Junction Temperature

75

50

0

25

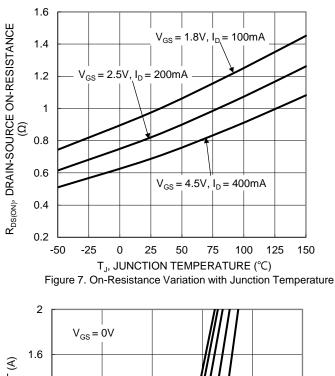
DMP31D1U Datasheet number: DS44735 Rev. 3 - 2  $V_{GS} = 1.8V, I_{D} = 100mA$ 

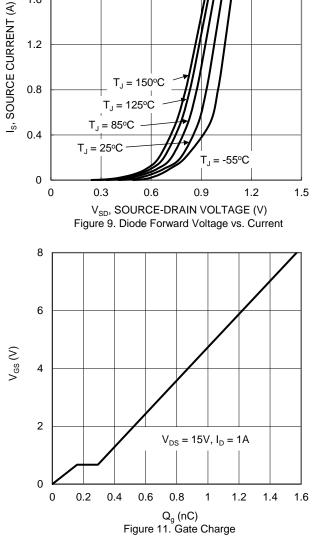
100

125

150

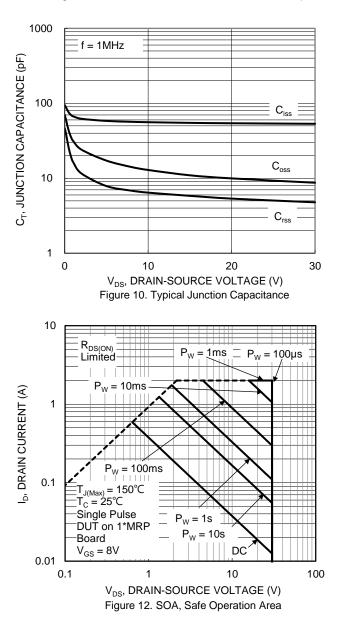






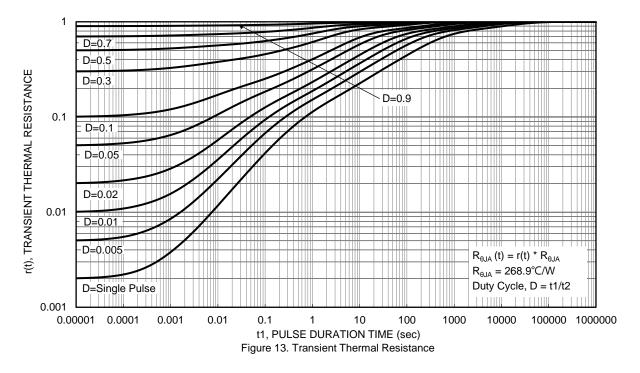
1  $V_{\text{GS(TH)}},$  GATE THRESHOLD VOLTAGE (V) 0.8  $I_D = 1 m A$ 0.6  $I_{D} = 250 \mu A$ 0.4 0.2 0 -25 25 50 75 100 125 150 -50 0 T<sub>J</sub>, JUNCTION TEMPERATURE (°C)





DMP31D1U Datasheet number: DS44735 Rev. 3 - 2

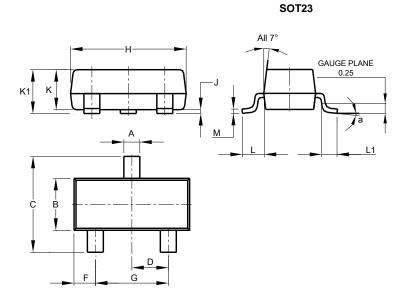






#### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



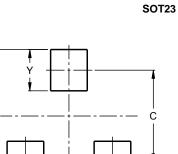
	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890 1.00		0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25 0.55		0.40					
М	0.085	0.150	0.110					
а	0°	8°	_					
All	Dimens	ions in	mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

Y٬

- X



Dimensions	Value (in mm)			
С	2.0			
Х	0.8			
X1	1.35			
Y	0.9			
Y1	2.9			



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 1N4002-T
 1N4003G-T

 1N4003-T
 1N4004
 1N4004G-T
 1N4005-B
 1N4005G-T
 1N4005-T
 1N4006-B
 1N4006G-T
 1N4006-T
 1N4007G-T

 1N4007-T
 1N4148W-13-F
 1N4148W-7-F
 1N4148WQ-13-F
 1N4148WS-13-F
 1N4148WS-7-F
 1N4148WQ-7-F
 1N4148WS-13-F
 1N4148WS-7-F
 1N4148WS-7-F